• Supplementary File •

## A Qi Compatible Wireless Power Receiver with Integrated Full-Wave Synchronous Rectifier

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## Appendix A Working Principles

When the AC1 signal is high, the MOSFETs MOS1 and MOS4 turn on, MOS2 and MOS3 turn off, and the current from the coil flows through MOS1 to the load and flows back from MOS4 to the coil, as shown in Figure A1(a).Conversely, when the AC2 signal is high, the MOSFETs MOS2 and MOS3 turn on, MOS1 and MOS4 turn off, and the current from the coil flows through MOS2 to the load and flows back from MOS3 to the coil, as shown in Figure A1(b).



Figure A1 The illustration of the synchronous control of the MOSFETs

The resistors R1 and R2 shown in Figure A1 are used to speed up the setup time of the output of the drivers. For example, when AC1 changes from low to high, the gate voltage of MOS1 follows AC1 to change from low to high due to the existence of R1, and then the driver outputs a high pulse to turn MOS1 on. As Figure A2(a) shows, the output of the driver changes from AC1 to BOOT1. If there is no resistor between the source and the gate, the output of the driver must change from zero to BOOT1, as shown in Figure A2(b), which is much higher than that in Figure A2(a). Therefore, the resistors R1 and R2 can shorten the setup time of the drivers and improve the power efficiency of the rectifier. The resistances of R1 and R2 are chosen as 5K considering the gate capacitance.

Figure A3 shows the block diagram of the proposed synchronous controller. The controller is used to generate the bidirectional non-overlapping clocks according to the polarity of the received AC input signal.

Figure A4 shows the timing diagram of the proposed digital pulse width controller. This controller uses the previous AC signal high-level width to generate a high pulse in the current AC cycle, and the high pulse is used to control the relevant high-side power MOSFETs to shut off before the AC signal changes from a high to low level. In this way, the turn-off delay could be eliminated effectively; therefore, the reverse leakage current is prevented, and the system efficiency can be improved.

Figure A5 illustrates the diagram of the non-overlapping clocks. The input signals are gotten from the output of the high-side voltage comparators, low-side voltage comparators, and the digital pulse width controller. The output signals are the non-overlapping clocks CLK\_N1, CLK\_N2, CLK\_N3, and CLK\_N4, which are used to control the relevant MOSFETs turn-on and turn-off to achieve a synchronous full wave rectifier. Figure A6 illustrates the timing diagram of the synchronous rectifier.

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Figure A2 The timing diagram of the gate voltage (a) with resistor (b) without resistor



Figure A3 The block diagram of the proposed synchronous control logic module



Figure A4 The timing diagram of the digital pulse width controller



Figure A5 The diagram of the non-overlapping clocks generator

## Appendix B Experimental results

Figure B1 shows the chip microphotograph, which occupied 9.9  $mm^2$ .

Figure B2 illustrates the measurement environment of the wireless power transfer system. The transmitter (TX) coil and the receiver (RX) coil are located at the bottom and the top side, respectively. The power is transferred from the transmitter board to the receiver board through the TX coil and the RX coil.

Figure B3 shows the measurement results for the wireless power receiver. When the receiver is placed on a transmitter and the transmitter powers on, the RX coil receives the power from the TX coil. Then, the rectifier works in a passive

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Figure A6 Timing diagram of the synchronous rectifier



 ${\bf Figure \ B1} \quad {\rm The \ chip \ microphotograph}$ 

Parameter	Transmitter	Receiver	
Coil Inductance	7µH	11.2µH	
Resonant Capacitance	400 nF	204 nF	
Resonant Frequency	95KHz	$106 \mathrm{KHz}$	
Vertical Dimension	4mm	$4\mathrm{mm}$	
Operation Frequency	110-205KHz	-	
Vin	$5\mathrm{V}$	-	

 ${\bf Table \ B1} \quad {\rm The \ main \ parameter \ of \ the \ system}$ 

diode mode to generate the RECT voltage, and the receiver starts working and communicating with the transmitter. When



Figure B2 Measure environments of the wireless power transfer system



Figure B3 Measurement results of the wireless power receiver

the output condition is satisfied, the output is enabled, and the receiver continues to communicate with the transmitter to dynamically control the RECT voltage according to the output power. The output power shown in Figure B3 is 5W, and the RECT voltage is finally close to the output voltage of 5V. As shown in the large view of Figure B3, from the AC1 signal wave we see that the synchronous rectifier can effectively eliminate the turn-off delay of the MOSFETs.

Figure B4 shows the measured power efficiency of the wireless power system. Table B1 shows the main parameters of this system. The output current is swept from 0.1A to 1A, and the peak power efficiency of the system is 82% at the 0.9A output current. Table B2 summarizes the comparison between related wireless power receivers reported elsewhere and in this paper. The maximum output power and the system efficiency in [1] is lower than that of this work. It is illustrated in [2] that the same maximum output power as does this paper, while the system efficiency of the wireless power receiver proposed in this paper is higher than that of [2]. The maximum output power in [3-5] is much smaller than that of in this paper.



Figure B4 The measured power efficiency of the wireless power system

Reference	[4]	[8]	[14]	[15]	[16]	This work
Technology	$0.18 \mu m$	N/A	$0.18 \mu m$	0.18µm	$0.18 \mu m$	0.18µm
	BCD		CMOS	CMOS	COMS	BCD
Working Frequency (KHz)	100-300	100-200	100-150	$13.56\mathrm{MHz}$	$13.56\mathrm{MHz}$	110-205
System Efficiency (%)	63@2.5W	(68-72)@ $(2.5-5)$ W	82@peak	70-87	55@peak	82@0.9A
Maximun Coil Separation dc(MAX)	N/A	$30\mathrm{mm}$	11mm	$20 \mathrm{mm}$	10mm	10mm
$_{ m Lp}$	N/A	N/A	$12.8 \mathrm{mH}$	$3.12~\mu H$	N/A	$11.2 \mu H$
CP	N/A	N/A	$110 \mathrm{pF}$	N/A	N/A	204 nF
$\mathrm{Ls}(\mu\mathrm{H})$	N/A	12.5	400	4.13	0.98	7
$\mathbf{Cs}$	N/A	N/A	No Cs	$33 \mathrm{pF}$	$141 \mathrm{pF}$	400 nF
Output Voltage (V)	3.5 to $5$	5	1.2	2.3 to 3	1.8	5
Max Output Power (W)	2.5	5	$224 \mu W$	$632 \mu W$	$12 \mu W$	5
Die Area $(mm^2)$	5.83	N/A	0.49	0.45	4.8	9.9

 Table B2
 Tabel Performance summary of the wireless power receiver system

## References

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